# VS-E4PU3006L-N3

**Vishay Semiconductors** 



### Ultrafast Soft Recovery Diode, 30 A FRED Pt<sup>®</sup> Gen 4



3 TO-247AD 2L	Cathode Anode
PRIMARY CHARACTI	ERISTICS
I <sub>F(AV)</sub>	30 A
V <sub>R</sub>	600 V
V <sub>F</sub> at I <sub>F</sub>	1.19 V
t <sub>rr</sub> typ.	see Recovery table
T <sub>J</sub> max.	175 °C
Package	TO-247AD 2L
Circuit configuration	Single

#### FEATURES

- Gen 4 FRED Pt<sup>®</sup> technology
- Low I<sub>RRM</sub> and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 131 °C	30	٨						
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 25 °C, $t_{p}$ = 8.3 ms half sine wave	240	A						
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)										
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP										
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-					
Forward voltage		I <sub>F</sub> = 30 A	-	1.36	1.6					
		I <sub>F</sub> = 60 A	-	1.6	-					
	V	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.23	-	V				
	V <sub>F</sub>	I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.5	-					
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.19	1.35	-				
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	-					
		V <sub>R</sub> = V <sub>R</sub> rated	-	-	50					
Reverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	18.3	-	pF				

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RoHS

COMPLIANT

HALOGEN



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	65	-	ns		
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>B</sub> = 400 V	-	90	-			
Pools receivers ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	18	-	A		
Peak recovery current		T <sub>J</sub> = 125 °C		-	32	-			
	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	850	-	nC		
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	1850	-			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.9					
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>		-	0.4	-					
Weight			-	6.0	-	g				
Weight			-	0.21	-	oz.				
Mounting torque			6.0 (5)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AD 2L		E4PU	3006L					

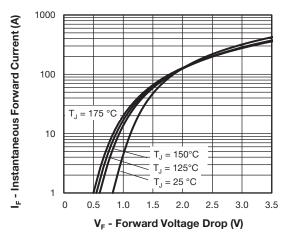


Fig. 1 - Typical Forward Voltage Drop Characteristics

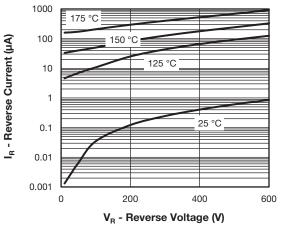


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



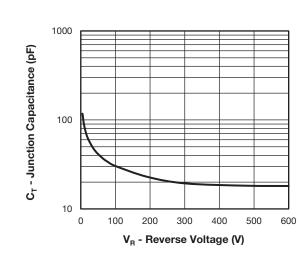


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

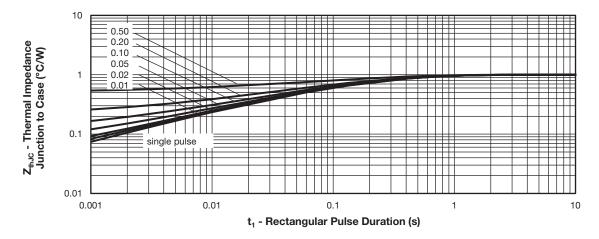
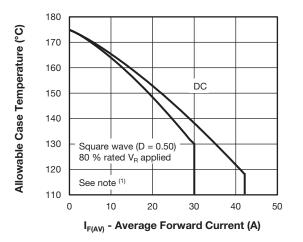
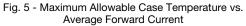


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics



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#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times V_{FM} \mbox{at } (\mbox{I}_{F(AV)}/D) \mbox{ (see Fig.5)} \\ \mbox{P}_{dREV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{(1 - D); } \mbox{I}_{R} \mbox{at } V_{R} = \mbox{rated } V_{R} \end{array}$ 

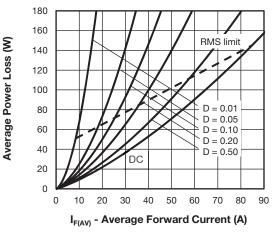


Fig. 6 - Forward Power Loss Characteristics

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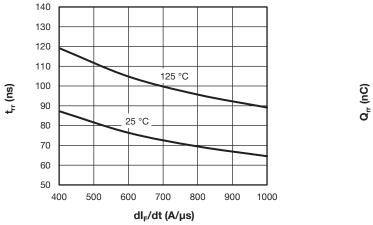


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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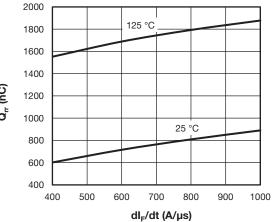


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

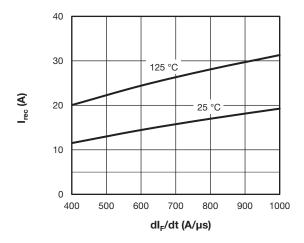


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt



#### **ORDERING INFORMATION TABLE**

Device code	VS-	Е	4	Р	U	30	06	L	-N3	
	1	2	3	4	5	6	7	8	9	
	1 -	1 - Vishay Semiconductors product								
	2 -	2 - Circuit configuration:								
	E = single diode									
	3 - FRED Pt Gen 4									
	4 -	P =	TO-247	' packag	e					
	5 -	Pro	cess typ	be:						
		U =	ultrafas	t recove	ery					
	6 - Current rating (30 = 30 A)									
	7 - Voltage rating (06 = 600 V)									
	8 - Package: L = long lead									
	9 -			ntal digit: en-free,		complia	nt, and	totally l	ead (Pb	

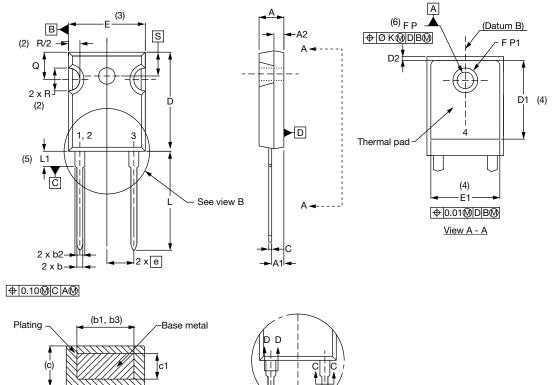
ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E4PU3006L-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95536							
Part marking information	www.vishay.com/doc?95648						



**TO-247AD 2L** 

#### **DIMENSIONS** in millimeters and inches



Section C - C, D - D

(b. b2)

(4)

/	$\square$
	C C
Vie	<u>w B</u>

SYMBOL	MILLIM	IETERS	INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			Е	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0	)10	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	
D2	0.51	1.35	0.020	0.053								

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

<sup>(2)</sup> Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

(7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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